

Corial 200 Series





200FA 200S 200R 210RL 200I 210IL 210D D250 D250L

RIE, ICP, ICP-CVD & PECVD Solutions
COMPOUND SEMICONDUCTORS | DIELECTRICS | METALS | SILICON

Your partner in plasma processing. Today and Tomorrow.

CORIAL is a leading provider of plasma etch and deposition process solutions and equipment which contributes to innovation in wafer processing for the semiconductor and microelectronic industries.

CORIAL addresses a range of end-market applications including MEMS, LEDs & OLEDs, power devices, advanced packaging, failure analysis, and wireless devices.

CORIAL at your service

- 1. More than 30 years experience in processing:
 - Silicon & Silicon Compounds
 - III-V & II-VI Compounds
 - Metals & Dielectrics
- Local support around the globe through a global network of offices and agents
- Versatility & flexibility of equipment that grow in capability as you do

The Corial 200 Series – versatile etch & deposition systems for R&D and production up to 200 mm

One common platform – but a whole host of handling and processing options makes the Corial 200 Series the perfect choice for R&D, development or production on substrate

Choose a module from the Corial 200 Series confident in the knowledge that your tool will deliver damage free processing with the highest repeatability over a number of processes.

sizes up to 200 mm.

The modules from the Corial 200 Series can be expanded with more gas lines and processes later, and your processes can be scaled up to Corial 300 Series platforms for higher throughputs or larger substrate sizes.

Corial 200 Series features:

- Flexibility in process technology: RIE, ICP, ICP+RIE, ICP-CVD, or PECVD modules based on one common platform.
- Flexibility in process chemistry: Run fluorinated and/or chlorinated chemistries in the same recipe without cross contamination.
- Flexibility in substrate size: Swap easily between 2, 4, 6, or 8 inch substrates.
- Flexibility in substrate handling: Select between 3 options depending on chemistry and throughout requirements: direct load, preloaded shuttle, or preloaded shuttle with load-lock.
- Minimum reactor maintenance: Reactors for contamination free processing with in situ plasma cleaning for reduced reactor maintenance.
- Software that puts you in control: Modules can be used in one of two ways: continuous wave plasma, or pulsed plasma processing.

Find the right tool for you	1	4	a. F			Carloss.	A STATE OF THE STA	-	
	RIE	RIE RIE, ICP or ICP+RIE		P or ICP+RIE	ICP-CVD	PECVD			
System	200FA	2008	200R	210RL	2001	210IL	210D	D250	D250L
Loading capacity	Die (to full wafer)	e (to full wafer) Wafer fragments = 7x2 = 3x3 (RIE) = 1x3" (ICP) = 1x4" = 1x6" = 1x8"						Wafer fragments - 7x2" - 3x3" - 2x4" - 1x6" - 1x8"	
Upgrade potential Gas lines / Loadlock / ICP	YES / NO / NO	YES / NO / NO	YES / YES / YES	YES / - / YES	YES / YES / -	YES / - / -	YES / - / -	YES / YES / NO	YES / - / NO
Substrate handling	Direct loading	Direct loading	Preloaded shuttle	Preloaded shuttle – transfer through loadlock	Preloaded shuttle	Preloaded shuttle - transfer through loadlock	Preloaded shuttle – transfer through loadlock	Preloaded shuttle	Preloaded shuttle - transfer through loadlock
Silicon compounds and polymer etching									
Metal etching with Fluorinated / Chlorinated chemistry / sputter-etch		□/-/□			■■■/-/□				
III-V Compounds Etching									
III-V Compounds Etching (low damage)									
II-VI Compounds Etching									
Hard materials (sapphire, quartz, etc)									
Failure Analysis									
High Temp dep (SiO2, Si3N4, aSi-H, SiC)								120°	C - 320°C
Low Temp dep (SiO2, Si3N4, aSi-H, SiC)							Up to 150°C	Up to 150°C	



ICP etch of InP with high aspect ratio



High resolution Si etch with high aspect ratio



PECVD deposition of 60 layer stack – 6nm SiO₂ then 4nm aSi–H in same recipe



Failure Analysis - Dielectric removal on die, wafer or packaged die

COUNT on us everywhere

Our sales and service network grows as our business expands around the globe. With support available from our partners in USA, Russia, China, India, Israel, Taiwan, Korea, Singapore and around Europe you are never far away from CORIAL know-how and our global Plasma-Therm/CORIAL sales and service teams.

Remote system access for systems check and operation and even download of processes direct to your machine through our Virtual Private Network (VPN) mean short response times, efficient service and rapid development of new processes in partnership with CORIAL process expertise in France.

Our applications lab is equipped with tools and a whole range of characterisation techniques to help you develop deposition & etch processes that run accurately, repeatedly and reliably in 24/7 production.







About us

With more than 30 years experience in delivering custom plasma deposition and etch systems, the CORIAL management and its team is based at Grenoble, just 1 hour away from the international airport of Geneva.

We design, build and test standard or custom platforms according to customer request. Contact us to hear about the latest updates on our products, services and global network.

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